

## **KSE45H Series**

### **General Purpose Power Switching Applications**

- Low Collector-Emitter Saturation Voltage: V<sub>CE</sub>(sat) = -1V (MAX)@-8A
- Fast Switching Speeds
- Complement to KSE44H



1.Base 2.Collector 3.Emitter

## **PNP Epitaxial Silicon Transistor**

### Absolute Maximum Ratings $T_C=25$ °C unless otherwise noted

Symbol	Parameter	Value	Units
$V_{CEO}$	Collector-Emitter Voltage : KSE45H 1,2	- 30	V
	: KSE45H 4,5	- 45	V
	: KSE45H 7,8	- 60	V
	: KSE45H 10,11	- 80	V
V <sub>EBO</sub>	Emitter- Base Voltage	- 5	V
I <sub>C</sub>	Collector Current (DC)	- 10	А
I <sub>CP</sub>	*Collector Current (Pulse)	- 20	А
P <sub>C</sub>	Collector Dissipation (T <sub>C</sub> =25°C)	50	W
P <sub>C</sub>	Collector Dissipation (T <sub>a</sub> =25°C)	1.67	W
T <sub>J</sub>	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	- 55 ~ 150	°C

## Electrical Characteristics $T_C=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
I <sub>CES</sub>	Collector Cut-off Current	$V_{CE}$ = Rated, $V_{CEO}$ , $V_{EB}$ = 0			-10	μΑ
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB} = -5V, I_{C} = 0$			-100	μΑ
h <sub>FE</sub>	*DC Current Gain : KSE45H 1, 4, 7 10 : KSE45H 2, 5, 8,11	V <sub>CE</sub> = - 1V, I <sub>C</sub> = - 2A	35 60			
V <sub>CE</sub> (sat)	*Collector-Emitter Saturation Voltage : KSE45H 1, 4, 7 10 : KSE45H 2, 5, 8,11	I <sub>C</sub> = -8A, I <sub>B</sub> = -0.8A I <sub>C</sub> = -8A, I <sub>B</sub> = -0.4A			-1 -1	V V
V <sub>BE</sub> (sat)	*Base-Emitter Saturation Voltage	I <sub>C</sub> = -8A, I <sub>B</sub> = -0.8A			-1.5	V
f <sub>T</sub>	Current Gain Bandwidth Product	$V_{CE} = -10V, I_{C} = -0.5A$		40		MHz
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> = - 10V, f = 1MHz		230		pF
t <sub>ON</sub>	Turn ON Time	$V_{CC} = 20V, I_{C} = -5A$		135		ns
t <sub>STG</sub>	Storage Time	$I_{B1} = -I_{B2} = -0.5A$		500		ns
t <sub>F</sub>	Fall Time			100		ns

<sup>\*</sup> Pulse test: PW≤300μs, Duty cycle≤2%

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I<sub>C</sub> = 10 I<sub>B</sub>

## **Typical Characteristics**

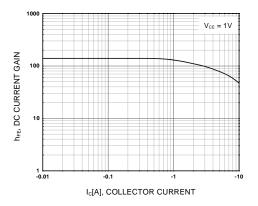


Figure 1. DC current Gain

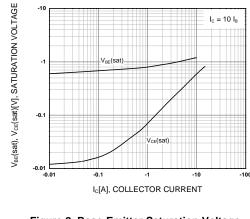


Figure 2. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

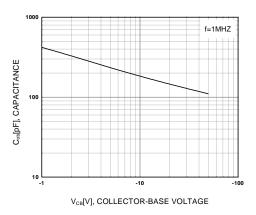


Figure 3. Collector Output Capacitance

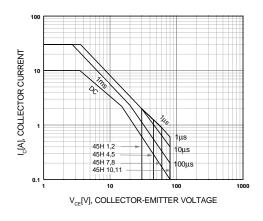


Figure 4. Safe Operating Area

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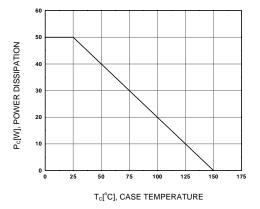
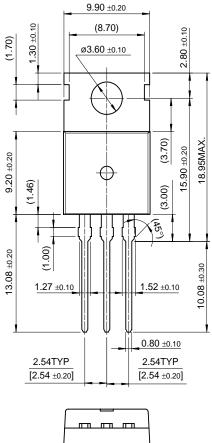


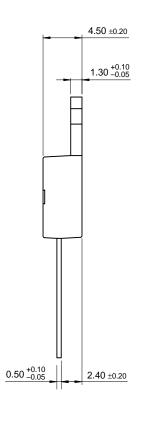
Figure 5. Power Derating

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# **Package Demensions**

## TO-220





10.00 ±0.20

Dimensions in Millimeters

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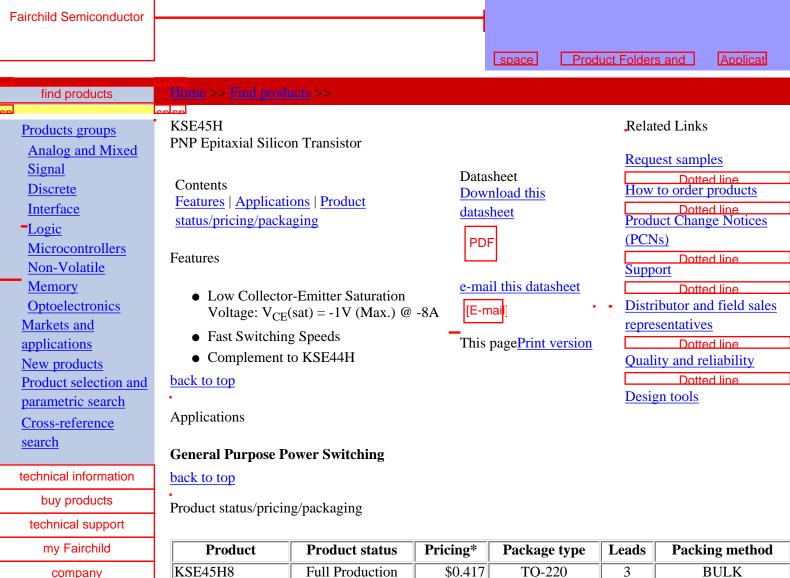
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Product	Product status	Pricing*	Package type	Leads	Packing method
KSE45H8	Full Production	\$0.417	TO-220	3	BULK
KSE45H8TU	Full Production	\$0.417	TO-220	3	RAIL
KSE45H11TU	Full Production	\$0.417	TO-220	3	RAIL
KSE45H11	Full Production	\$0.417	TO-220	3	BULK

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